



MODEL MM2425P50B
2.4~2.5GHz
100 WATTS
NARROW BAND POWER RF AMPLIFIER

Advantages:

- Operating Frequency :2.4~2.5GHz
- Power Gain:50dB Typical
- Psat:100W Typical
- Supply Voltage:+28V
- 50 Ohms Input and Output Matched

ELECTRICAL SPECIFICATIONS @ +28VDC, 25°C, 50Ω

Parameter	Symbol	Min	Typ	Max	Units
Operating Frequency	BW	2.4		2.5	GHz
RF Output Power @Pin=0dBm	P _{SAT}		100		Watt
Power Gain	G _p		50		dB
Power Gain Flatness	Δ G _p		±1.5		dB
Input Return Loss	S ₁₁			-10	dB
Harmonics @60W	H		-15		dBc
Spurious Signals	Spur		-60		dBc
Switch On/Off@10-90% Time,1kHz	T _{ON/OFF}		2		μS
In/Output Impedance	Impedance		50		Ω
Operating Voltage	V _{DC}	24	28	32	Volt
DC Current @100W	I _{DD}		10		Amp

MECHANICAL SPECIFICATIONS

Parameter	Value	Units	Notes
Dimensions	180x90x25 [7.09x3.54x0.98]	mm [inch]	Maximum
Weight	2.0 [4.4]	kg [lbs]	Maximum
RF Connectors Input	SMA, Female		
RF Connectors Output	SMA, Female		
DC Interface Connector	Hybrid, D-Sub 7-Pin, Male		
Cooling	External Heatsink Required (Not Supplied)		

ENVIRONMENTAL CHARACTERISTICS (Design to Meet)

Parameter	Minimum	Typical	Maximum	Units	Notes
Operating Temperature	-40		60	°C	
Non-operating Temperature	-45		85	°C	Storage
Relative Humidity (non-condensing)			95	%	

ABSOLUTE MAXIMUM RATING

Input RF drive level without damage	+5 dBm (Max)
Load VSWR @ P _{OUT} =40W	∞ @ all load phase & amplitude for duration of 1 minute; 3:1 @ all load phase & amplitude continuous.
Over Temperature	85° C @ heatsink [restored @ 60° C]

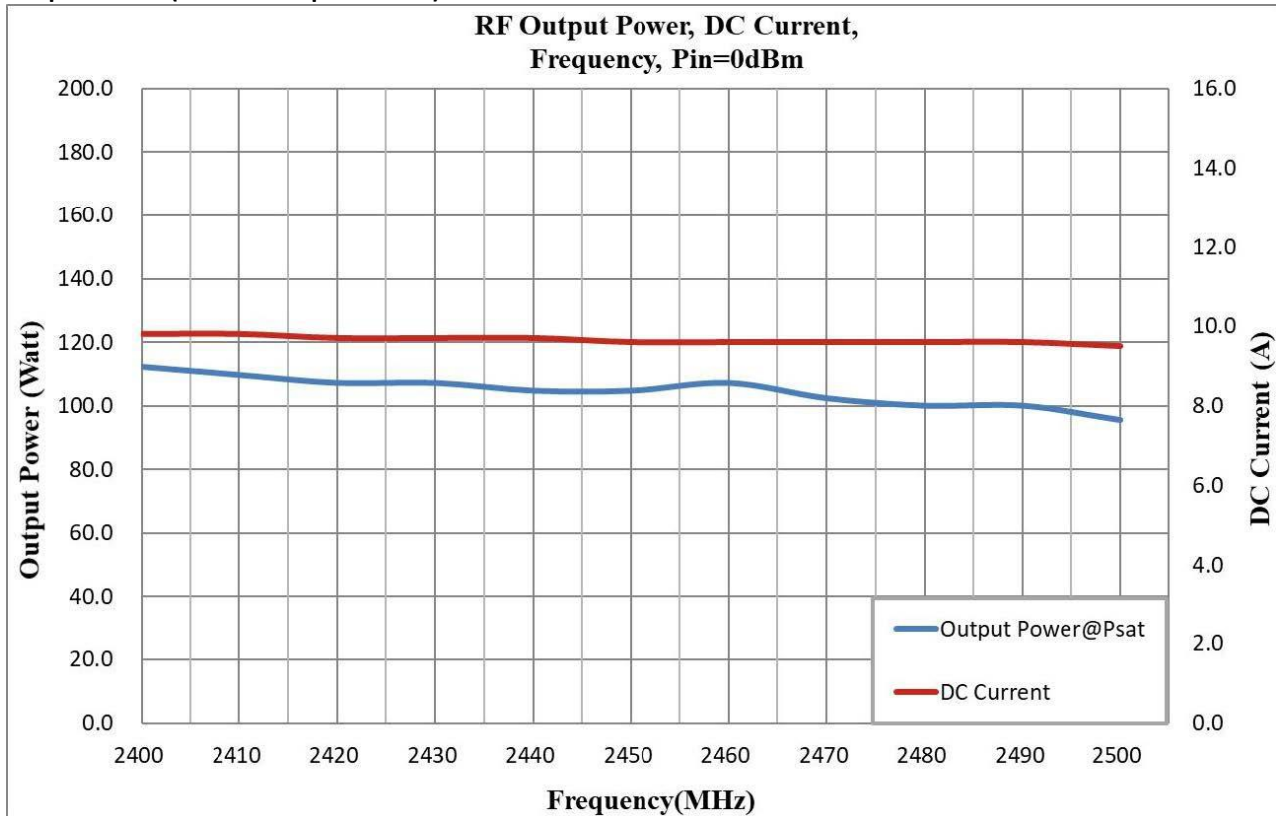
POWER INTERFACE CONNECTOR

Male D-Sub is on the housing

Pin #	Description	Specifications
A1	VDD	28VDC
A2	GND	Ground
1	SHUTDOWN	Amplifier Disable: TTL Logic High (3.3V~5V) (Internally Pulled-Low)
2	CURRENT SENSE	Analog voltage relative to IDD @ 100mV per Ampere
3	TEMP SENSE	Analog voltage relative to Module's Temperature @ 0.5V+10 mV/°C
4	GND	Ground
5	GND	Ground

TYPICAL PERFORMANCE PLOTS (FOR REFERENCE ONLY)

Output Power (Normal temp. +25±3°C)



Note: Adequate heatsink required.